

# Chip Termination 150 Watts, 50Ω



#### Features:

- RoHS Compliant
- 150 Watts
- DC 3.0 GHz
- AIN Ceramic
- Non-Nichrome Resistive
  Element
- Low VSWR
- 100% Tested

# **Description**

The A150N50X4E is high performance Aluminum Nitride (AIN) chip termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators and for use in power combiners. The termination is also RoHS compliant!

#### **General Specifications**

Resistive Element	Thick film
Substrate	AIN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-50 to +200°C (see de rating chart)

Tolerance is  $\pm 0.010"$ , unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.

### **Electrical Specifications**

Resistance Value:	50 Ohms, ± 2%
Power:	150 Watts
Frequency Range:	DC –3.0 GHz
Return Loss	25dB DC – 2.0 GHz 20dB DC – 3.0 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.** 

#### **Outline Drawing**







# **Typical Performance:**



#### **Power De-rating:**

**Mounting Footprint and Procedure:** 



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